

TOSHIBA PHOTOCOUPLER GaAs IRED & PHOTO-TRANSISTOR

TLP121

OFFICE MACHINE

PROGRAMMABLE CONTROLLERS

AC/DC-INPUT MODULE

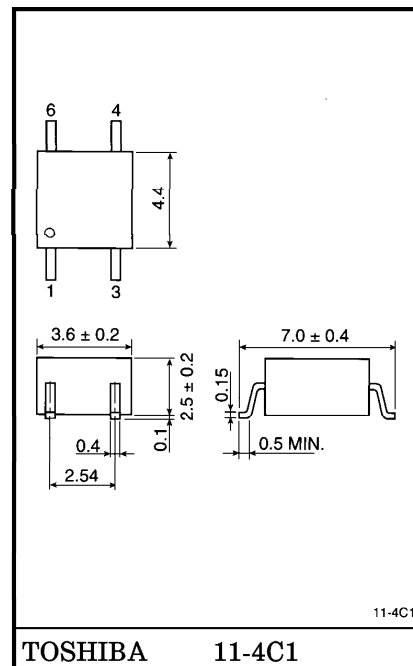
TELECOMMUNICATION

The TOSHIBA MINI FLAT COUPLER TLP121 is a small outline coupler, suitable for surface mount assembly.

TLP121 consists of a photo transistor, optically coupled to a gallium arsenide infrared emitting diode.

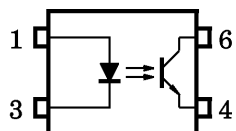
- Collector-Emitter Voltage : 80V (Min.)
- Current Transfer Ratio : 50% (Min.)
Rank GB : 100% (Min.)
- Isolation Voltage : 3750Vrms (Min.)
- UL Recognized : UL 1577, File No. E67349

Unit in mm



Weight : 0.09g

PIN CONFIGURATIONS (TOP VIEW)



- 1 : ANODE
- 3 : CATHODE
- 4 : EMITTER
- 6 : COLLECTOR

CURRENT TRANSFER RATIO

TYPE	CLASSIFICATION *1	CURRENT TRANSFER RATIO (%) (I _C / I _F)		MARKING OF CLASSIFICATION
		I _F =5mA, V _{CE} =5V, T _a =25°C		
		MIN.	MAX.	
TLP121	(None)	50	600	BLANK, Y, Y [■] , G, G [■] , B, B [■] , GB
	Rank Y	50	150	Y, Y [■]
	Rank GR	100	300	G, G [■]
	—	200	600	B, B [■]
	Rank GB	100	600	G, G [■] , B, B [■] , GB

*1 : Ex, Rank GB : TLP121 (GB)

Note : Application type name for certification test, please use standard product type name, i, e.

TLP121 (GB) : TLP121

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	RATING	UNIT
LED	Forward Current	I _F	50	mA
	Forward Current Derating	$\Delta I_F / ^\circ\text{C}$	-0.7 (Ta $\geq$ 53°C)	mA / °C
	Pulse Forward Current	I _{FP}	1 (100 μ s pulse, 100pps)	A
	Reverse Voltage	V _R	5	V
	Junction Temperature	T _j	125	°C
DETECTOR	Collector-Emitter Voltage	V _{CEO}	80	V
	Emitter-Collector Voltage	V _{ECO}	7	V
	Collector Current	I _C	50	mA
	Collector Power Dissipation	P _C	150	mW
	Collector Power Dissipation Derating (Ta $\geq$ 25°C)	$\Delta P_C / ^\circ\text{C}$	-1.5	mW / °C
	Junction Temperature	T _j	125	°C
Storage Temperature Range		T _{stg}	-55~125	°C
Operating Temperature Range		T _{opr}	-55~100	°C
Lead Soldering Temperature		T _{sol}	260 (10s)	°C
Total Package Power Dissipation		P _T	200	mW
Total Package Power Dissipation Derating (Ta $\geq$ 25°C)		$\Delta P_T / ^\circ\text{C}$	-2.0	mW / °C
Isolation Voltage (Note 1)		BV _S	3750 (AC, 1min., R.H. $\leq$ 60%)	V _{rms}

(Note 1) Device considered a two terminal device : Pins 1, 3 shorted together and pins 4, 6 shorted together

RECOMMENDED OPERATING CONDITIONS

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply Voltage	V _{CC}	—	5	48	V
Forward Current	I _F	—	16	20	mA
Collector Current	I _C	—	1	10	mA
Operating Temperature	T _{opr}	-25	—	85	°C

INDIVIDUAL ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
LED	Forward Voltage	V _F	I _F =10mA	1.0	1.15	1.3	V
	Reverse Current	I _R	V _R =5V	—	—	10	μA
	Capacitance	C _T	V=0, f=1MHz	—	30	—	pF
DETECTOR	Collector-Emitter Breakdown Voltage	V _(BR) CEO	I _C =0.5mA	80	—	—	V
	Emitter-Collector Breakdown Voltage	V _(BR) ECO	I _E =0.1mA	7	—	—	V
	Collector Dark Current	I _{CEO}	V _{CE} =48V	—	10	100	nA
			V _{CE} =48V, T _a =85°C	—	2	50	μA
	Capacitance (Collector to Emitter)	C _{CE}	V=0, f=1MHz	—	10	—	pF

COUPLED ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Current Transfer Ratio	I_C / I_F	$I_F = 5\text{mA}, V_{CE} = 5\text{V}$ Rank GB	50	—	600	%
			100	—	600	
Saturated CTR	$I_C / I_{F(\text{sat})}$	$I_F = 1\text{mA}, V_{CE} = 0.4\text{V}$ Rank GB	—	60	—	%
			30	—	—	
Collector-Emitter Saturation Voltage	$V_{CE(\text{sat})}$	$I_C = 2.4\text{mA}, I_F = 8\text{mA}$	—	—	0.4	V
		$I_C = 0.2\text{mA}, I_F = 1\text{mA}$ Rank GB	—	0.2	—	
			—	—	0.4	
Off-State Collector Current	$I_{C(\text{off})}$	$V_F = 0.7\text{V}, V_{CE} = 48\text{V}$	—	1	10	μA

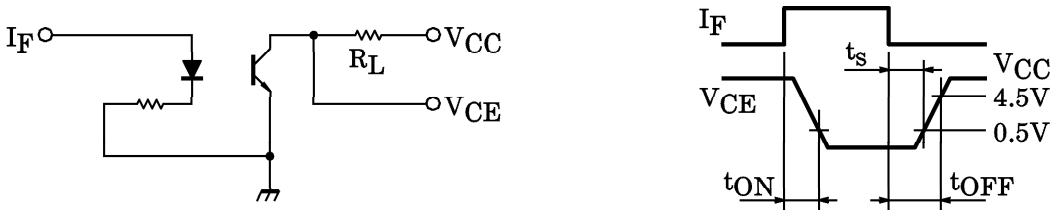
ISOLATION CHARACTERISTICS (Ta = 25°C)

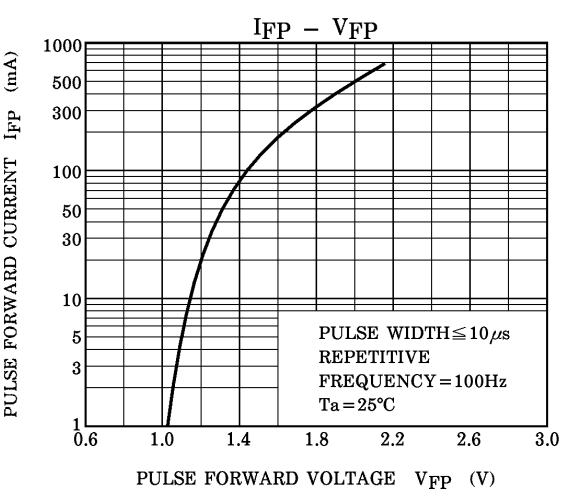
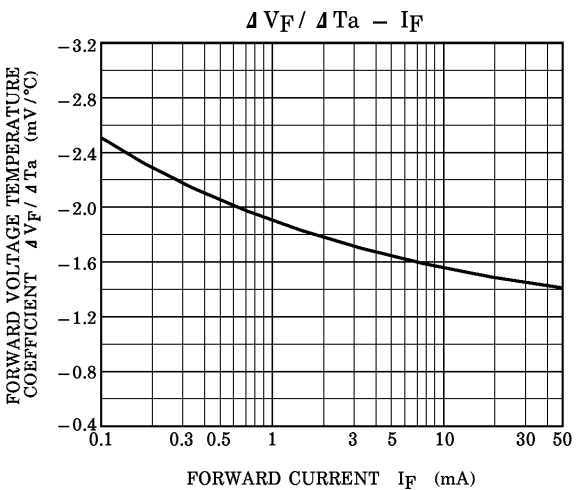
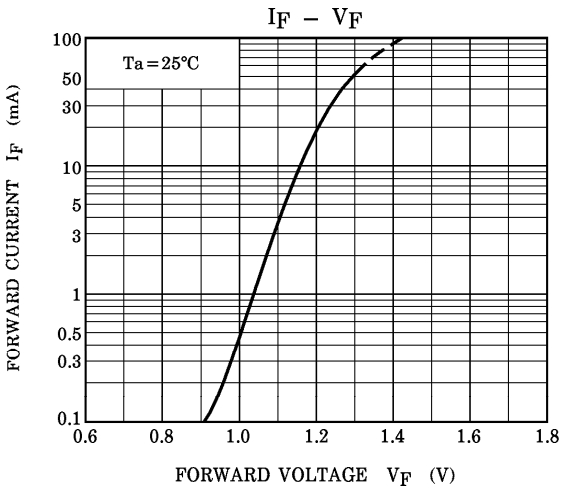
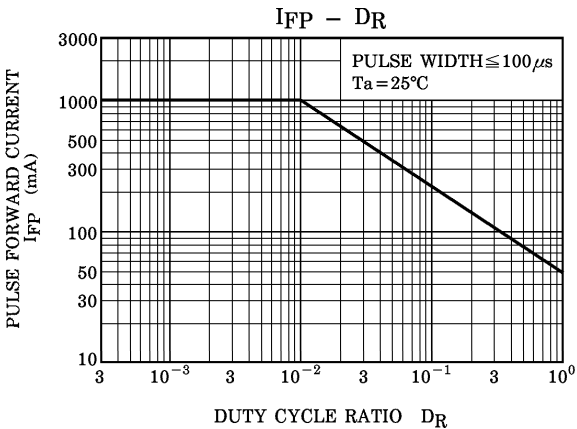
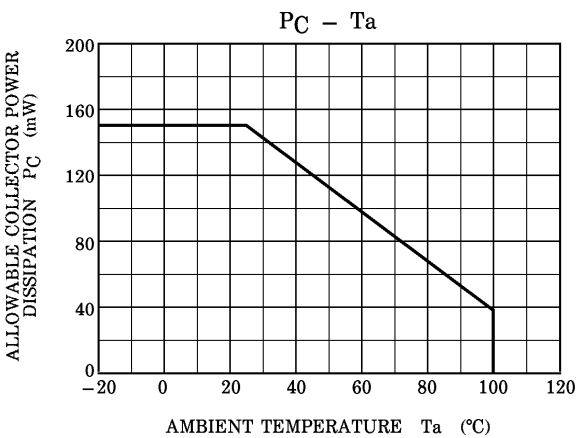
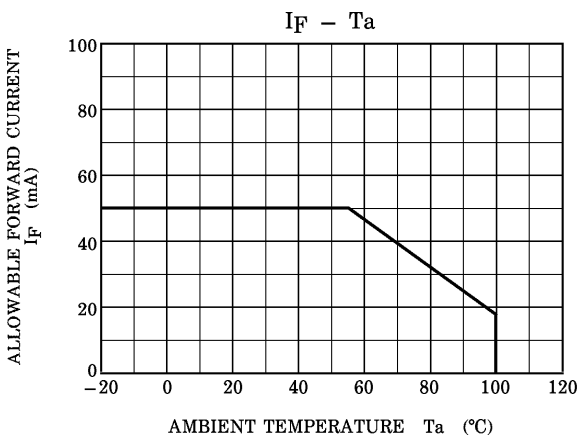
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Capacitance (Input to Output)	C_S	$V_S = 0, f = 1\text{MHz}$	—	0.8	—	pF
Isolation Resistance	R_S	$V_S = 500\text{V}, \text{R.H.} \leq 60\%$	5×10^{10}	10^{14}	—	Ω
Isolation Voltage	BV_S	AC, 1 minute	3750	—	—	V_{rms}
		AC, 1 second, in oil	—	10000	—	
		DC, 1 minute, in oil	—	10000	—	Vdc

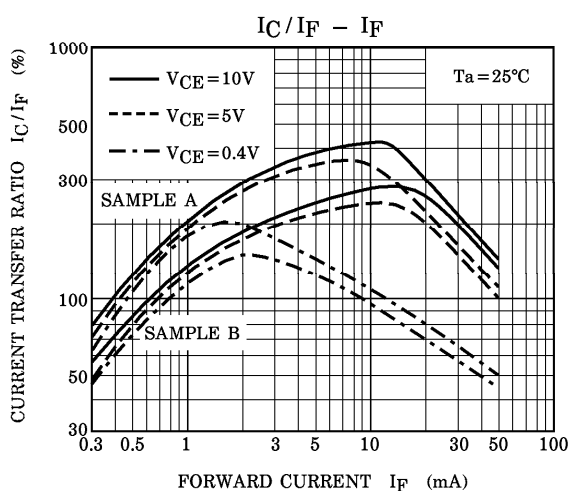
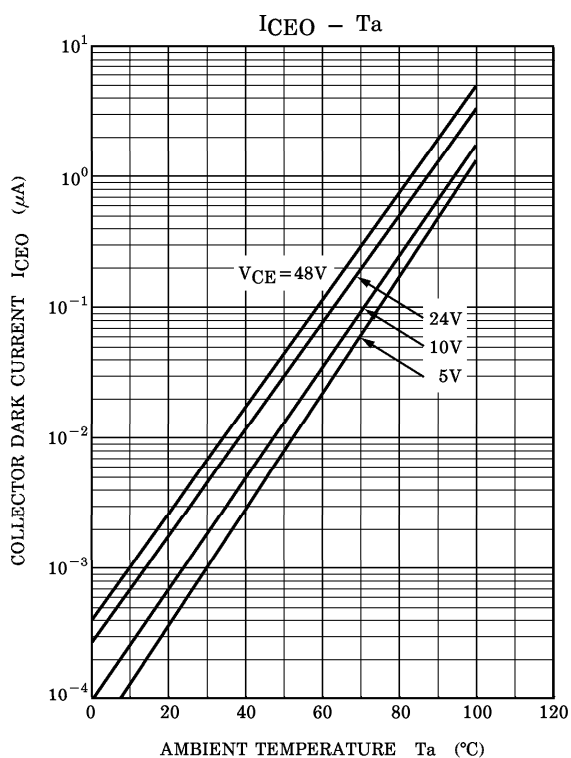
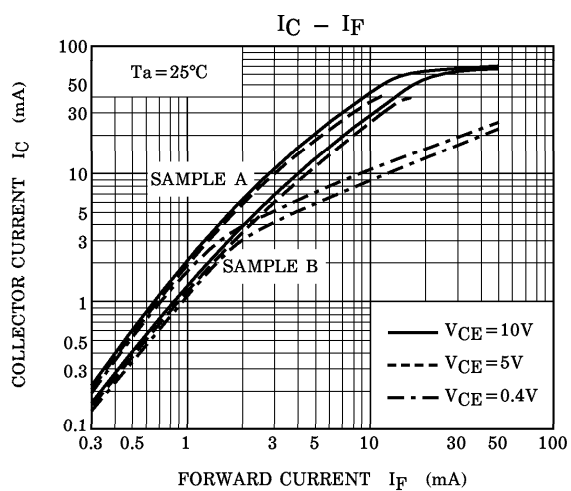
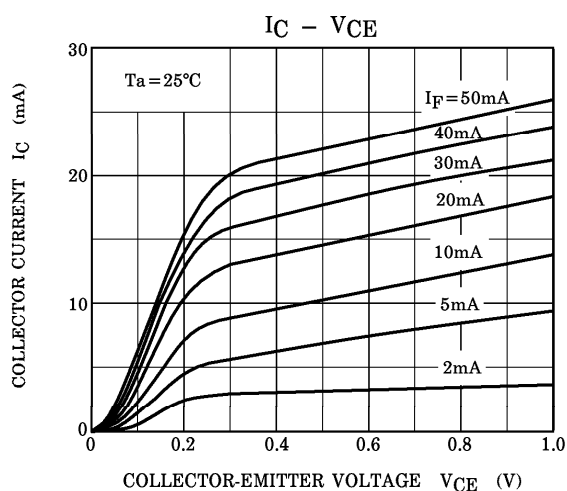
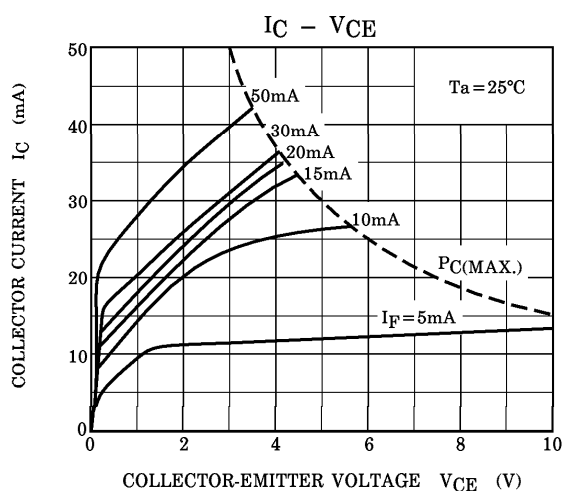
SWITCHING CHARACTERISTICS (Ta = 25°C)

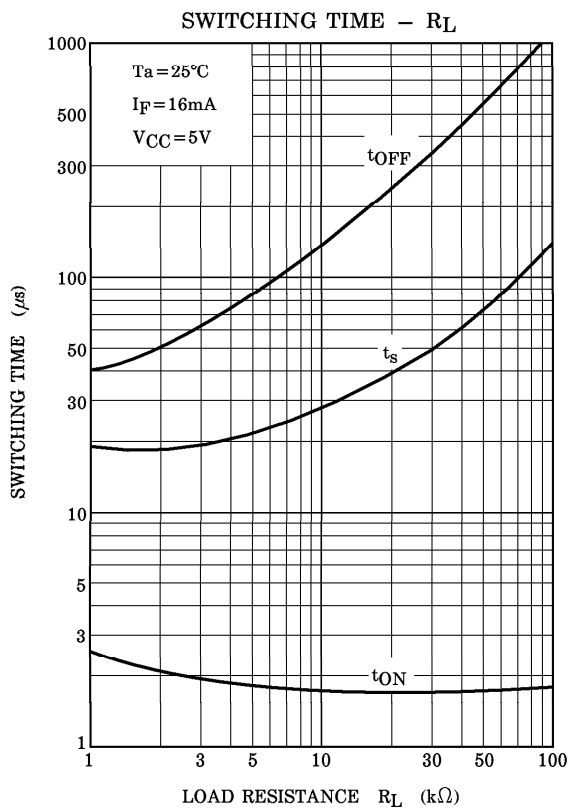
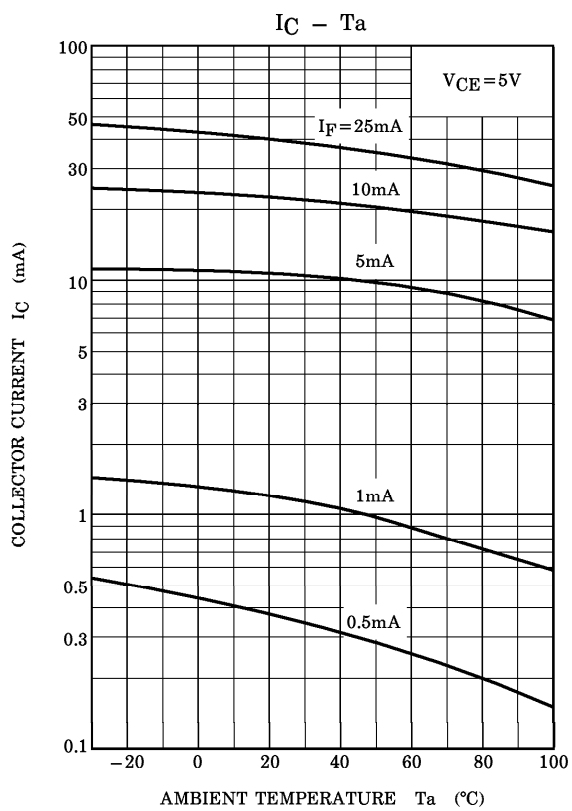
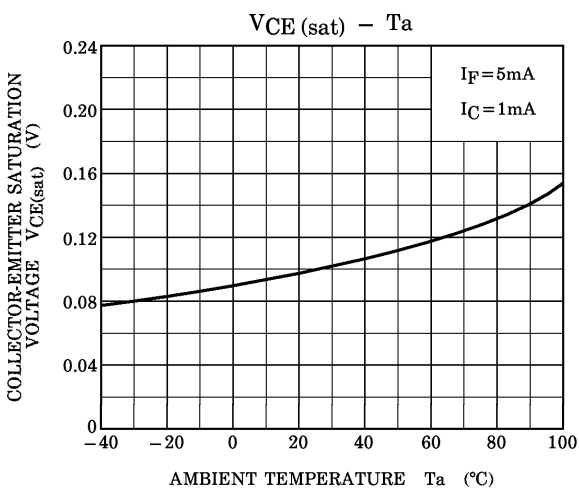
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Rise Time	t_r	$V_{CC} = 10V, I_C = 2mA$ $R_L = 100\Omega$	—	2	—	μs
Fall Time	t_f		—	3	—	
Turn-on Time	t_{on}		—	3	—	
Turn-off Time	t_{off}		—	3	—	
Turn-on Time	t_{ON}	$R_L = 1.9k\Omega$ (Fig.1) $V_{CC} = 5V, I_F = 16mA$	—	2	—	μs
Storage Time	t_s		—	25	—	
Turn-off Time	t_{OFF}		—	40	—	

Fig.1 SWITCHING TIME TEST CIRCUIT









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